

M1MA151KT1, M1MA152KT1

Preferred Device

Single Silicon Switching Diodes

These Silicon Epitaxial Planar Diodes are designed for use in ultra high speed switching applications. These devices are housed in the SC-59 package which is designed for low power surface mount applications.

Features

- Fast t_{rr} , < 3.0 ns
- Low C_D , < 2.0 pF
- Available in 8 mm Tape and Reel
 - Use M1MA151/2KT1 to order the 7 inch/3000 unit reel.
 - Use M1MA151/2KT3 to order the 13 inch/10,000 unit reel.
- Pb-Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Rating		Symbol	Value	Unit
Reverse Voltage	M1MA151KT1	V_R	40	Vdc
	M1MA152KT1		80	
Peak Reverse Voltage	M1MA151KT1	V_{RM}	40	Vdc
	M1MA152KT1		80	
Forward Current		I_F	100	mAdc
Peak Forward Current		I_{FM}	225	mAdc
Peak Forward Surge Current		I_{FSM} (Note 1)	500	mAdc

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

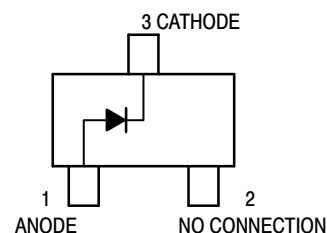
1. $t = 1 \text{ SEC}$



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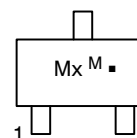
<http://onsemi.com>

SC-59 PACKAGE SINGLE SILICON SWITCHING DIODES 40/80 V-100 mA SURFACE MOUNT



SC-59
CASE 318D

MARKING DIAGRAM



Mx = Device Code
x = H for 151
I for 152
M = Date Code*
■ = Pb-Free Package
(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

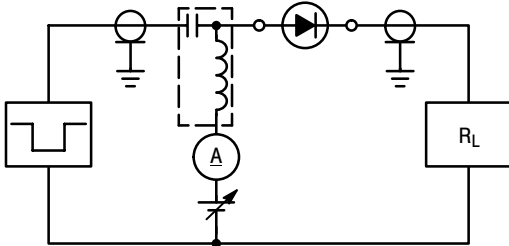
M1MA151KT1, M1MA152KT1

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

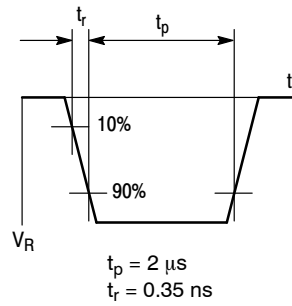
Characteristic		Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Current	M1MA151KT1	I _R	V _R = 35 V	–	0.1	μAdc
	M1MA152KT1		V _R = 75 V	–	0.1	
Forward Voltage		V _F	I _F = 100 mA	–	1.2	Vdc
Reverse Breakdown Voltage	M1MA151KT1	V _R	I _R = 100 μA	40	–	Vdc
	M1MA152KT1			80	–	
Diode Capacitance		C _D	V _R = 0, f = 1.0 MHz	–	2.0	pF
Reverse Recovery Time (Figure 1)		t _{rr} (Note 2)	I _F = 10 mA, V _R = 6.0 V, R _L = 100 Ω, I _{rr} = 0.1 I _R	–	3.0	ns

2. t_{rr} Test Circuit

RECOVERY TIME EQUIVALENT TEST CIRCUIT



INPUT PULSE



OUTPUT PULSE

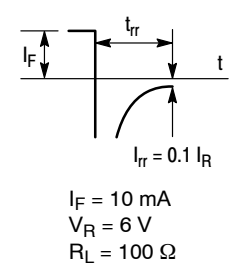


Figure 1. Reverse Recovery Time Equivalent Test Circuit

ORDERING INFORMATION

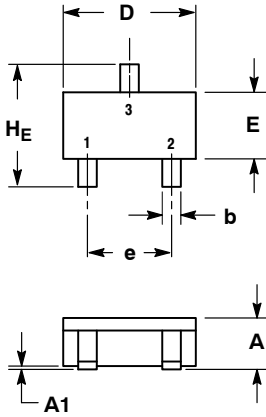
Device	Package	Shipping†
M1MA151KT1	SC-59	3000 Units / Tape & Reel
M1MA151KT1G	SC-59 (Pb-Free)	3000 Units / Tape & Reel
M1MA152KT1	SC-59	3000 Units / Tape & Reel
M1MA152KT1G	SC-59 (Pb-Free)	3000 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

M1MA151KT1, M1MA152KT1

PACKAGE DIMENSIONS

SC-59
CASE 318D-04
ISSUE H



NOTES:

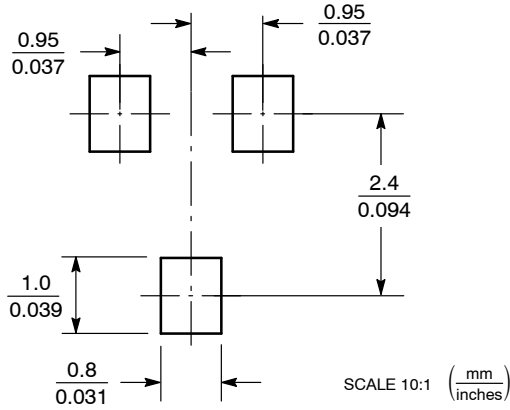
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.35	0.43	0.50	0.014	0.017	0.020
c	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

STYLE 2:

- PIN 1. ANODE
- N.C.
- CATHODE

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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M1MA151KT1/D

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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